

# isc N-Channel Mosfet Transistor

# BUZ255

### • FEATURES

- High speed switching
- Low  $R_{DS(ON)}$
- Easy driver for cost effective application
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### • DESCRIPTION

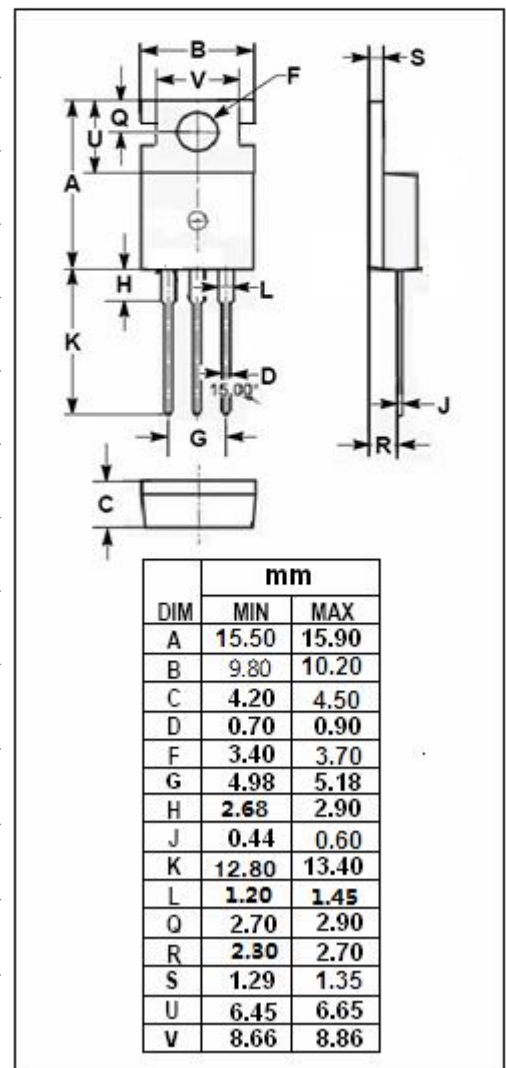
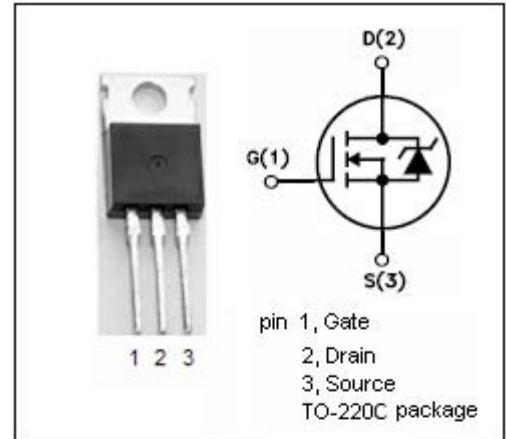
- Automotive power actuator drivers
- Motor controls
- DC-DC converters

### • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage ( $V_{GS}=0$ )	250	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-continuous@ $TC=31^\circ\text{C}$	13	A
$I_{DM}$	Drain Current-Single Pulsed	52	A
$P_{tot}$	Total Dissipation@ $TC=25^\circ\text{C}$	95	W
$T_j$	Max. Operating Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1.32	$^\circ\text{C/W}$
$R_{th\ j-a}$	Thermal Resistance, Junction to Ambient	75	$^\circ\text{C/W}$



**isc N-Channel Mosfet Transistor**
**BUZ255**
**ELECTRICAL CHARACTERISTICS**

 T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =0.25mA	250			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =1mA	2.1		4.0	V
V <sub>SD</sub>	Diode Forward On-voltage	I <sub>S</sub> = 26A; V <sub>GS</sub> = 0			1.6	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 8.5A			0.24	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =250V; V <sub>GS</sub> = 0			1	μA
G <sub>fs</sub>	Forward Transconductance	V <sub>DS</sub> = 25V; I <sub>D</sub> =8.5A	5.0			S
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>GS</sub> =10V; I <sub>D</sub> =3A; V <sub>DD</sub> =30V; R <sub>GS</sub> =50 Ω			25	ns
t <sub>r</sub>	Rise Time				90	
t <sub>d(off)</sub>	Turn-off Delay Time				250	
t <sub>f</sub>	Fall Time				80	

**Notice:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.